NSN 5961-00-433-1982

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-433-1982 **Inclosure Material:** Metal **Overall Length:** 0.405 inches **Overall Diameter:** 0.424 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 36.0 regulator voltage **Current Rating Per Characteristic:** 70.00 milliamperes repetitive peak forward current **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure:**

Demilitarization: No Fiig: A110a0